TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC21F,TC74VHC21FN,TC74VHC21FT

Dual 4-Input AND Gate

The TC74VHC21 is an advanced high speed CMOS 4-INPUT AND GATE fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

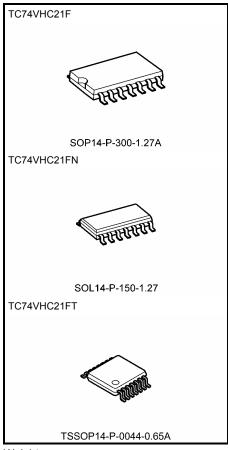
The internal circuit is composed of 4 stages including a buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $t_{pd} = 3.3 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- · Power down protection is provided on all inputs.
- Balanced propagation delays: t_pLH ≃ t_pHL
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Pin and function compatible with 74ALS21

Note: xxxFN (JEDEC SOP) is not available in Japan.

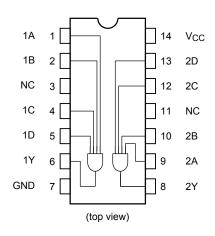


Weight

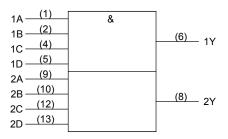
SOP14-P-300-1.27A : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

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Pin Assignment



IEC Logic Symbol



Truth Table

	Inp	Output			
Α	В	С	D	Υ	
L	Χ	Х	Х	L	
Х	L	Х	Х	L	
Х	Х	L	Х	L	
Х	Х	Х	L	L	
Н	Н	Н	Н	Н	

X: Don't care

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _C C	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
input rise and rail time	ui/uv	0 to 20 (V _{CC} = 5 ± 0.5 V)	115/ V	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Тур.	Max	Min	Max	0
High-level input		_		2.0	1.50	_	_	1.50	_	
voltage	V _{IH}			3.0 to 5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_	V
Low-level input		_		2.0	_	_	0.50	_	0.50	
voltage	V _{IL}			3.0 to 5.5	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V
	Vон	$V_{IN} = V_{IH}$		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	_	
High-level output voltage				4.5	4.4	4.5	_	4.4	_	V
			$I_{OH} = -4 \text{ mA}$	3.0	2.58		_	2.48	_	
			$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_	
	V _{OL} V ₌	V _{IN} = V _{IH} or V _{IL}		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 50 \mu A$	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage				4.5	_	0.0	0.1	_	0.1	V
			$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44	
			$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	$V_{IN} = 5.5 \text{ V or GND}$		0 to 5.5	_		±0.1	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	2.0	_	20.0	μА



AC Characteristics (input: $t_r = t_f = 3$ ns)

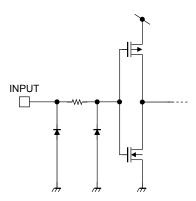
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
Propagation delay time	^t pLH –		3.3 ± 0.3	15	_	4.8	7.0	1.0	8.5	- ns
				50	_	7.3	10.5	1.0	12.0	
		_	5.0 ± 0.5	15	_	3.3	5.0	1.0	6.0	
			5.0 ± 0.5	50	_	4.8	7.0	1.0	8.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)		20	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

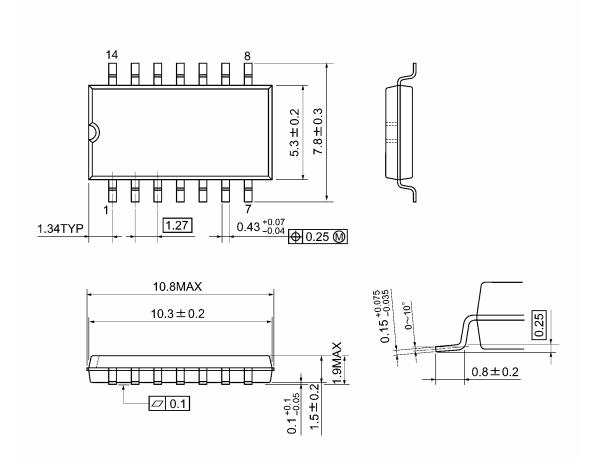
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per gate)}$$

Input Equivalent Circuit



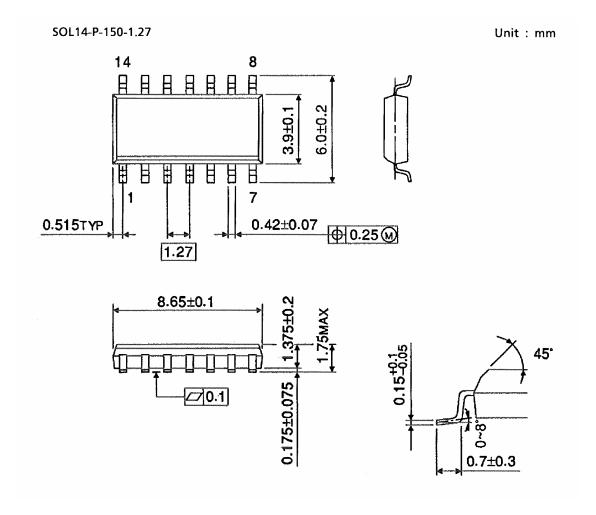
Package Dimensions

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

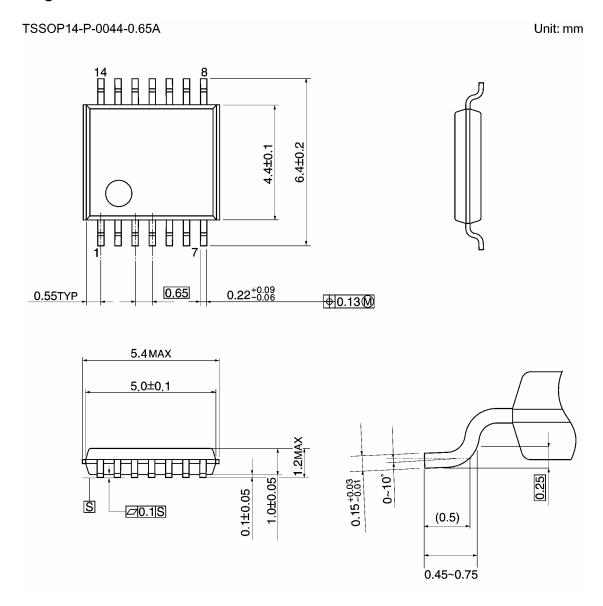
Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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